NSN 5961-00-952-8283

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Inclosure Material:

Metal

Overall Length:

0.350 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Internal Junction Configuration:

Pnp

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

45.0 breakdown voltage, collector-to-base, emitter open and 40.0 collector to emitter voltage, dc and 20.0 emitter to base voltage, dc

Current Rating Per Characteristic:

7.00 amperes source cutoff current and 3.00 amperes source cutoff current

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius case

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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